

	<h2>SI7886ADP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7886ADP-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 15A PPAK SO-8</p> <p>Datenblätter:  SI7886ADP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 101130 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7886ADP-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 15A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	101130 pcs Stock
detaillierte Beschreibung	N-Channel 30V 15A (Ta) 1.9W (Ta) Surface Mount
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	15A (Ta)
Rds On (Max) @ Id, Vgs	4 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	6450pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)





































SI7886ADP-T1-GE3 ist neu im Original, Suche SI7886ADP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7886ADP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7886ADP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7888DP SILICONIX SI7888DP SILICONIX</p>	 <p>SI7886DP-T1-GE3 Vishay Precision Group SI7886DP-T1-GE3 VISHAY</p>	 <p>SI7886A SIL SI7886A SIL</p>	 <p>SI7886ADP-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 15A PPAK SO-8</p>
 <p>SI7886DP-T1-E3 VISHAY SI7886DP-T1-E3 VISHAY</p>	 <p>SI7884DP-T1-GE3 V SI7884DP-T1-GE3 V</p>	 <p>SI7886DP-T1 VISHAS SI7886DP-T1 VISHAS</p>	 <p>SI7886ADP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 15A PPAK SO-8</p>

heiße Teile

Mehr

 SI786LG-T1	 SI786LG-T1-E3	 SI7872DP	 SI7872DP-T1-E3	 SI7872DP-T1-E3
 SI7872DP-T1-GE3	 SI7872DP-T1-GE3	 SI7880ADP-T1-E3	 SI7880ADP-T1-E3	 SI7880ADP-T1-GE3
 SI7880ADP-T1-GE3	 SI7880DP-T1-GE3	 SI7882DP-T1-E3	 SI7882DP-T1-E3	 SI7882DP-T1-GE3
 SI7882DP-T1-GE3	 SI7884BDP	 SI7884BDP-T1-E3	 SI7884BDP-T1-E3	 SI7884BDP-T1-GE3
 SI7884BDP-T1-GE3	 SI7884DP-T1-E3	 SI7884DP-T1-GE3	 SI7886ADP-T1-E3	 SI7886ADP-T1-E3
 SI7886ADP-T1-GE3	 SI7886DP	 SI7886DP-T1	 SI7886DP-T1-E3	 SI7886DP-T1-GE3
 SI7888DP-T1-E3	 SI7888DP-T1-E3	 SI7888DP-T1-GE3	 SI7888DP-T1-GE3	 SI7892ADP-T1-E3
 SI7892ADP-T1-GE3	 SI7892ADP-T1-GE3.	 SI7892BDP-T1-E3	 SI7892BDP-T1-E3	 SI7892BDP-T1-GE3
 SI7892BDP-T1-GE3	 SI7892DP	 SI7892DP-T1	 SI7892DP-T1-E3	 SI7892DP-T1-GE3
 SI7898DP	 SI7898DP-T1-E3	 SI7898DP-T1-E3	 SI7898DP-T1-GE3	 SI7898DP-T1-GE3

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